

Super Barrier Rectifier™

Using state-of-the-art SBR IC process technology, the following features are made possible in a single device:

Major ratings and characteristics

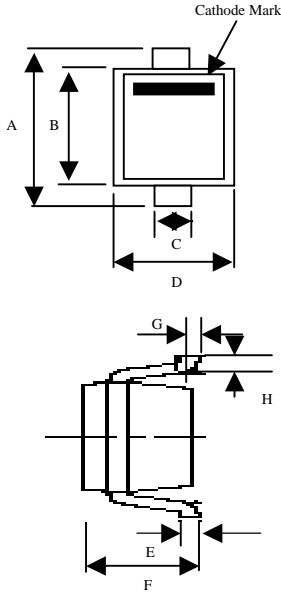
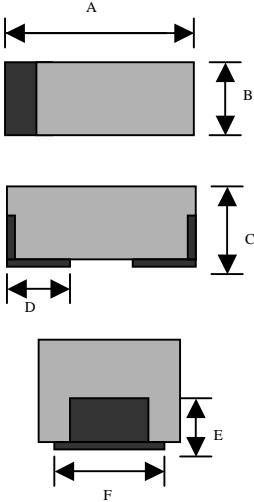
Characteristics	Values	Units
$I_{F(AV)}$ Rectangular Waveform	0.10	A
V_{RRM}	40	V
$V_F @ 0.1A, T_J = 75^\circ C$	0.43	V, typ
T_J (operating/storage)	-65 to 125	$^\circ C$

ELECTRICAL:

- * Low Forward Voltage Drop
- * Low Reverse Leakage
- * Reliable High Temperature Operation
- * Super Barrier Design
- * Softest, fast switching capability
- * 125 $^\circ C$ Operating Junction Temperature

MECHANICAL:

- * Molded Plastic SOD-323, SOD-523 packages

SBR0140S3	SBR0140S5																																																						
<div style="text-align: center;">  <p style="margin-top: 10px;">SOD-323</p> </div> <table border="1" style="margin: 10px auto; border-collapse: collapse; text-align: center;"> <thead> <tr style="background-color: #ffff00;"> <th colspan="3">SOD-323</th> </tr> <tr> <th>Di</th> <th>Min</th> <th>Max</th> </tr> </thead> <tbody> <tr><td>A</td><td>2.30</td><td>2.70</td></tr> <tr><td>B</td><td>1.60</td><td>1.80</td></tr> <tr><td>C</td><td>0.25</td><td>0.40</td></tr> <tr><td>D</td><td>1.15</td><td>1.45</td></tr> <tr><td>E</td><td>0.10</td><td>0.18</td></tr> <tr><td>F</td><td>0.85</td><td>1.05</td></tr> <tr><td>G</td><td>-</td><td>0.10</td></tr> <tr><td>H</td><td>0.20</td><td>0.40</td></tr> </tbody> </table> <p style="text-align: center; font-size: small;">All Dimensions in mm</p>	SOD-323			Di	Min	Max	A	2.30	2.70	B	1.60	1.80	C	0.25	0.40	D	1.15	1.45	E	0.10	0.18	F	0.85	1.05	G	-	0.10	H	0.20	0.40	<div style="text-align: center;">  <p style="margin-top: 10px;">SOD-523</p> </div> <table border="1" style="margin: 10px auto; border-collapse: collapse; text-align: center;"> <thead> <tr style="background-color: #ffff00;"> <th colspan="3">SOD-523</th> </tr> <tr> <th>Di</th> <th>Min</th> <th>Max</th> </tr> </thead> <tbody> <tr><td>A</td><td>1.60</td><td>1.80</td></tr> <tr><td>B</td><td>0.8</td><td>1.0</td></tr> <tr><td>C</td><td>0.70</td><td>0.85</td></tr> <tr><td>D</td><td colspan="2">0.35 (typ)</td></tr> <tr><td>E</td><td colspan="2">0.30 (typ)</td></tr> <tr><td>F</td><td colspan="2">0.70 (typ)</td></tr> </tbody> </table> <p style="text-align: center; font-size: small;">All Dimensions in mm</p>	SOD-523			Di	Min	Max	A	1.60	1.80	B	0.8	1.0	C	0.70	0.85	D	0.35 (typ)		E	0.30 (typ)		F	0.70 (typ)	
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Maximum Ratings and Electrical Characteristics (at 25°C unless otherwise specified)				
	SYMBOL			UNITS
DC Blocking Voltage Working Peak Reverse Voltage Peak Repetitive Reverse Voltage	V_{RM} V_{RWM} V_{RRM}	40		Volts
Average Rectified Forward Current (Rated V_R - 20Khz Square Wave) - 50% duty cycle	I_o	0.10		Amps
Peak Forward Surge Current - 1/2 60hz	I_{FSM}	2		Amps
Instantaneous Forward Voltage $I_F = 100mA; T_J = 25^\circ C$ $I_F = 100mA; T_J = 75^\circ C$	V_F	Typ --- ---	Max 0.49 0.46	Volts
Maximum Reverse Current at Rated V_{RM} $T_J = 25^\circ C$ $T_J = 75^\circ C$	I_R^*	Typ --- ---	Max 5 200	uA uA
Operating and Storage Junction Temperature	T_J	-65 to +125		°C

NOTE: Dice are available for customer applications.

* Pulse width < 300 uS, Duty cycle < 2%

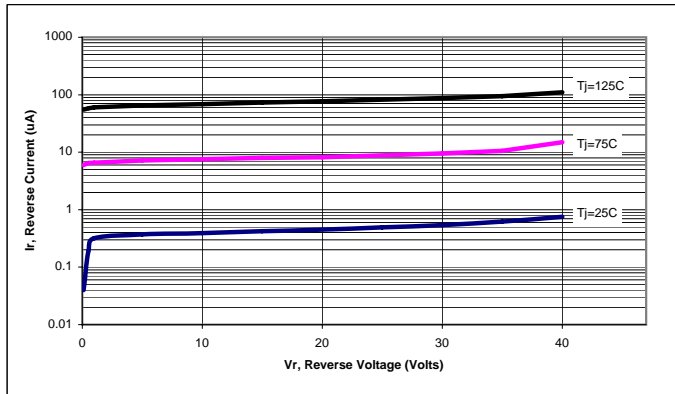


Figure 1: Typical Reverse Current

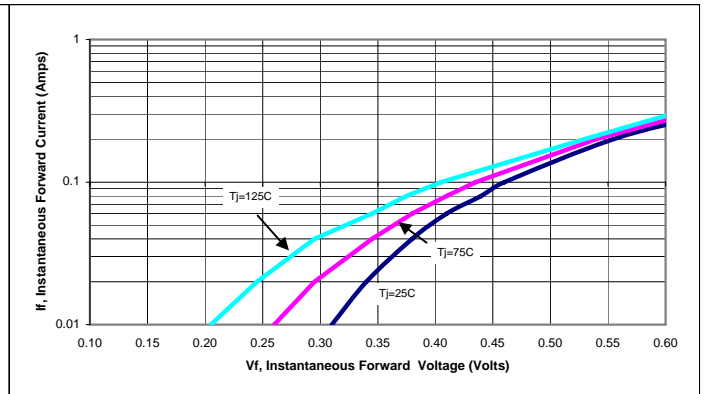


Figure 2: Typical Forward Voltage

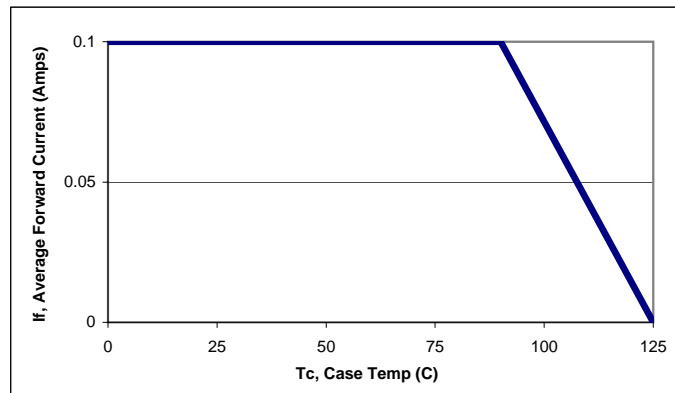


Figure 3: Current Derating, Case

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